DPDT SWITCH GaAs MMIC

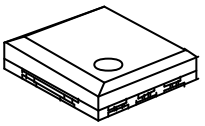
■GENERAL DESCRIPTION

NJG1528HD3 is a GaAs high power DPDT switch MMIC for antenna switch of tri- and dual-mode cellular phone application such as CDMA, AMPS and PCS.

This switch features low loss, high isolation at high power.

The ultra small & ultra thin USB6-D3 package is applied.

■PACKAGE OUTLINE

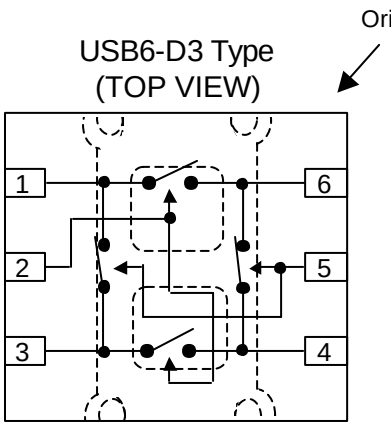


NJG1528HD3

■FEATURES

●Low voltage operation	2.5V min.
●Pin at 0.2dB compression point	36dBm typ. @f=1.9GHz, V_{CTL}=2.8V
●Low insertion loss	0.60dB typ. @f=0.9GHz, P_{IN}=31dBm, V_{CTL}=2.8V
	0.70dB typ. @f=1.9GHz, P_{IN}=25dBm, V_{CTL}=2.8V
●High isolation	23dB typ. @f=0.9GHz, P_{IN}=31dBm, V_{CTL}=2.8V
	17dB typ. @f=1.9GHz, P_{IN}=25dBm,V_{CTL}=2.8V
●Low control current	10uA typ. @f=0.9GHz, P_{IN}=31dBm, V_{CTL}=2.8V
●Ultra small & ultra thin package	USB6-D3 (Package size: 2.0x1.8x0.8mm)

■PIN CONFIGURATION



Pin connection

1. P1
2. VCTL1
3. P2
4. P3
5. VTL2
6. P4

■TRUTH TABLE

ON Pass	VCTL1	VCTL2
P1-P2	L	H
P3-P4	L	H
P1-P4	H	L
P2-P3	H	L

NOTE: Please note that any information on this catalog is subject to change.

■ABSOLUTE MAXIMUM RATINGS

(T_a=+25°C, Z_s=Z_l=50Ω)

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNITS
RF Input Power	P_{IN}	$V_{CTL(L)}$=0V, $V_{CTL(H)}$=3V	37.5	dBm
Operating Voltage	V_{CTL}	$V_{CTL(H)}$-$V_{CTL(L)}$	12	V
Power Dissipation	P_D		200	mW
Operating Temp.	T_{opr}		-40~+85	°C
Storage Tempe.	T_{stg}		-55~+150	°C

■ELECTRICAL CHARACTERISTICS

(General conditions: T_a=+25°C, Z_s=Z_l=50Ω, $V_{CTL\ (L)}$=0V, $V_{CTL\ (H)}$=2.8V)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Control Voltage (Low)	$V_{CTL\ (L)}$	f=0.01~2.5GHz	-0.2	0	0.2	V
Control Voltage (High)	$V_{CTL\ (H)}$	f=0.01~2.5GHz	2.5	2.8	6.5	V
Control Current	I_{CTL}	f=0.9GHz, P_{IN}=31dBm	-	10	20	uA
Insertion loss 1	LOSS1	f=0.9GHz, P_{IN}=31dBm	-	0.60	0.75	dB
Insertion loss 2	LOSS2	f=1.9GHz, P_{IN}=25dBm	-	0.75	0.90	dB
Isolation 1 (P1-P2, P3-P4, P1-P4 P2-P3, P1-P3, P2-P4)	ISL1	f=0.9GHz, P_{IN}=31dBm	21	23	-	dB
Isolation 2 (P1-P2, P3-P4, P1-P4 P2-P3, P1-P3, P2-P4)	ISL2	f=0.9GHz, P_{IN}=31dBm	16	17	-	dB
Pin at 0.2dB Compression point	$P_{-0.2dB}$	f=1.9GHz	33.5	36	-	dBm
2nd Harmonics 1	2fo(1)	f=0.9GHz, P_{IN}=25dBm	-	-	-70	dBc
2nd Harmonics 2	2fo(2)	f=1.9GHz, P_{IN}=25dBm	-	-	-65	dBc
3rd Harmonics 1	3fo(1)	f=0.9GHz, P_{IN}=25dBm	-	-	-65	dBc
3rd Harmonics 2	3fo(2)	f=1.9GHz, P_{IN}=25dBm	-	-	-65	dBc
Input 3 rd order intercept Point 1	IIP3(1)	f=900+901MHz, Pin=25dBm *1	-	60	-	dBm
Input 3 rd order intercept Point 2	IIP3(2)	f=1900+1901MHz, Pin=25dBm *1	-	60	-	dBm
VSWR	$VSWR_i$	on-state ports, f=1.9GHz	-	1.2	1.4	
Switching time	T_{SW}	f=0.1~2.5GHz	-	100	-	ns

*1: The input IP3 is defined as following equation.
IIP3=(3 x Pout - IM3) / 2 + LOSS

■TERMINAL INFORMATION

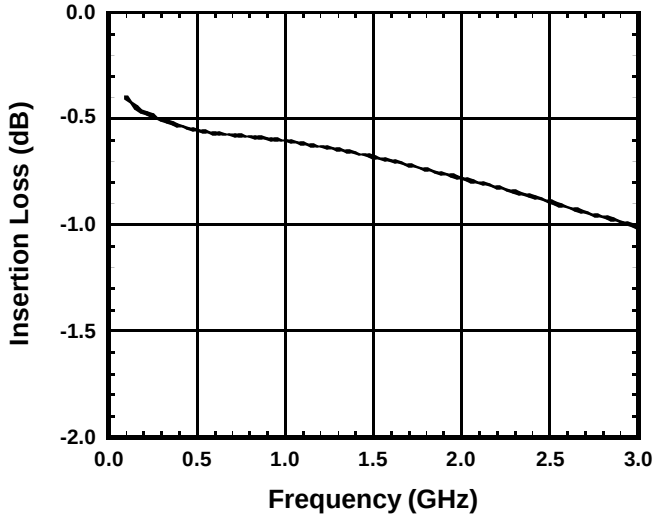
No.	SYMBOL	EXPLANATION
1	P1	RF port. This port is connected with P2 port by controlling 2pin-$V_{CTL(H)}$ (+2.5~+6.5V) and 5pin-$V_{CTL(L)}$ (-0.2~+0.2V). This port is connected with P4 port by controlling 2pin-$V_{CTL(L)}$ (-0.2~+0.2V) and 5pin-$V_{CTL(H)}$ (+2.5~+6.5V). A DC cut capacitor 56pF is reguired at this terminal to block DC voltage of inner circuit.
2	VCTL1	Control port1. Please connect bypass capacitor (10pF) between this terminal and GND close to this IC.
3	VCTL2	Control port2. Please connect bypass capacitor (10pF) between this terminal and GND close to this IC.
4	P2	RF port. This port is connected with P1 port by controlling 2pin-$V_{CTL(L)}$ (-0.2~+0.2V) and 5pin-$V_{CTL(H)}$ (+2.5~+6.5V). This port is connected with P3 port by controlling 2pin-$V_{CTL(H)}$ (+2.5~+6.5V) and 5pin-$V_{CTL(L)}$ (-0.2~+0.2V). A DC cut capacitor 56pF is reguired at this terminal to block DC voltage of inner circuit.
5	P3	RF port. This port is connected with P2 port by controlling 2pin-$V_{CTL(H)}$ (+2.5~+6.5V) and 5pin-$V_{CTL(L)}$ (-0.2~+0.2V). This port is connected with P4 port by controlling 2pin-$V_{CTL(L)}$ (-0.2~+0.2V) and 5pin-$V_{CTL(H)}$ (+2.5~+6.5V). A DC cut capacitor 56pF is reguired at this terminal to block DC voltage of inner circuit.
6	P4	RF port. This port is connected with P1 port by controlling 2pin-$V_{CTL(H)}$ (+2.5~+6.5V) and 5pin-$V_{CTL(L)}$ (-0.2~+0.2V). This port is connected with P3 port by controlling 2pin-$V_{CTL(L)}$ (-0.2~+0.2V) and 5pin-$V_{CTL(H)}$ (+2.5~+6.5V). A DC cut capacitor 56pF is reguired at this terminal to block DC voltage of inner circuit.

■ELECTRICAL CHARACTERISTICS

(with application circuit, losses of PCB, connector and DC blocking capacitor are excluded)

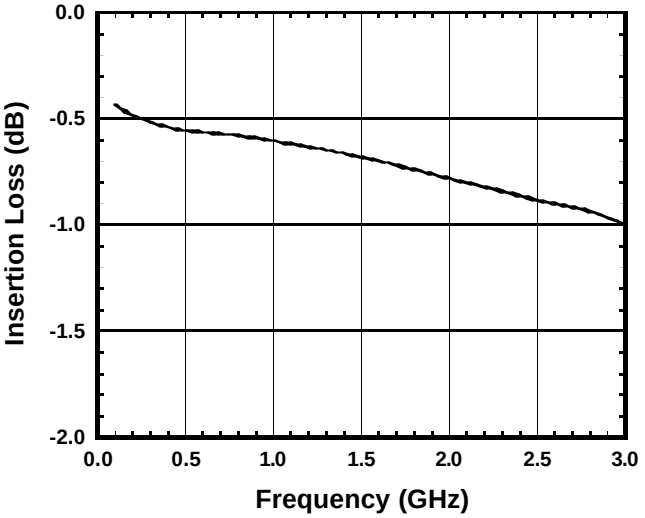
P1-P2 Insertion Loss vs. Frequency

(P1-P2/P3-P4 ON, VCTL=0V/2.8V, Pin=-10dBm)



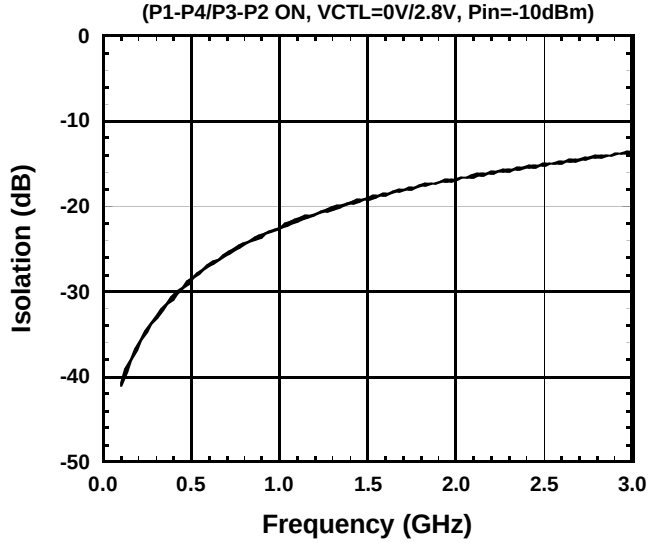
P3-P4 Insertion Loss vs. Frequency

(P1-P2/P3-P4 ON, VCTL=0V/2.8V, Pin=-10dBm)



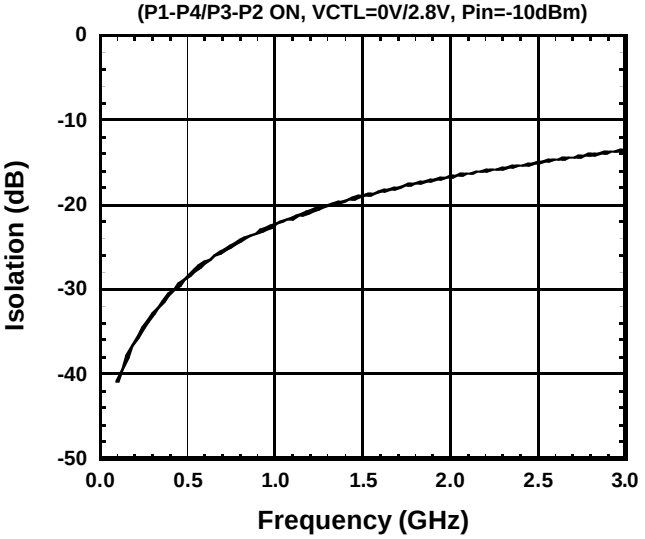
P1-P2 Isolation vs. Frequency

(P1-P4/P3-P2 ON, VCTL=0V/2.8V, Pin=-10dBm)



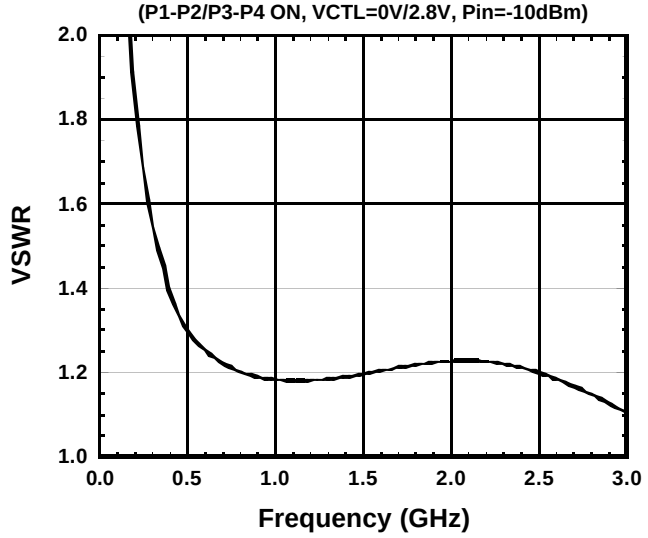
P3-P4 Isolation vs. Frequency

(P1-P4/P3-P2 ON, VCTL=0V/2.8V, Pin=-10dBm)



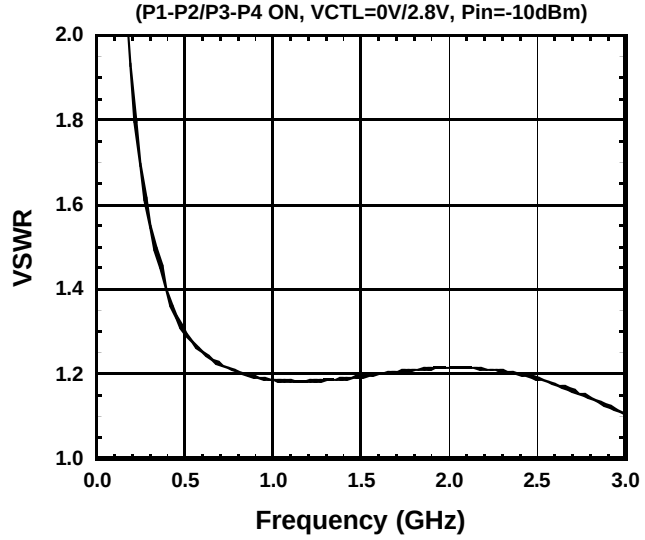
P1-P2 VSWR vs. Frequency

(P1-P2/P3-P4 ON, VCTL=0V/2.8V, Pin=-10dBm)



P3-P4 VSWR vs. Frequency

(P1-P2/P3-P4 ON, VCTL=0V/2.8V, Pin=-10dBm)

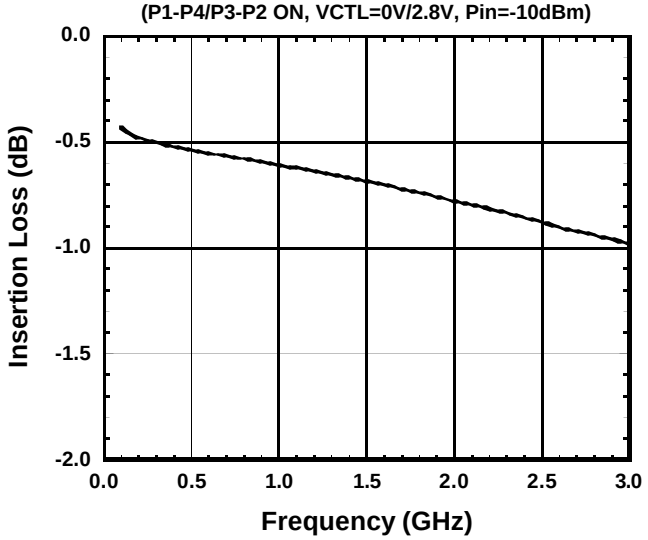


■ELECTRICAL CHARACTERISTICS

(with application circuit, losses of PCB, connector and DC blocking capacitor are excluded)

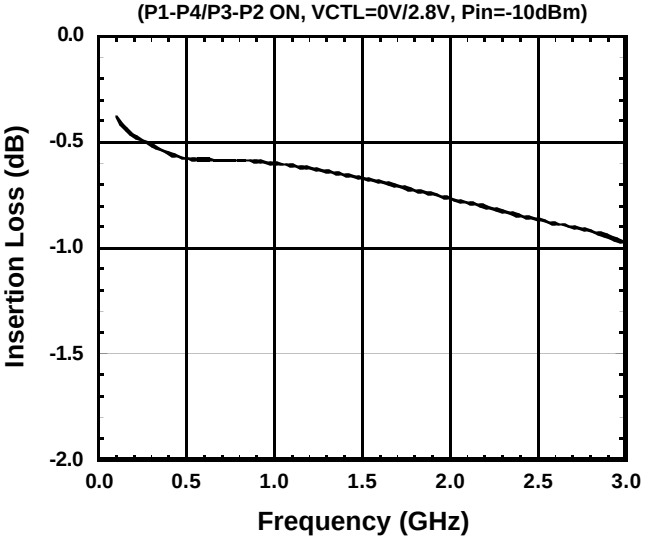
P1-P4 Insertion Loss vs. Frequency

(P1-P4/P3-P2 ON, VCTL=0V/2.8V, Pin=-10dBm)



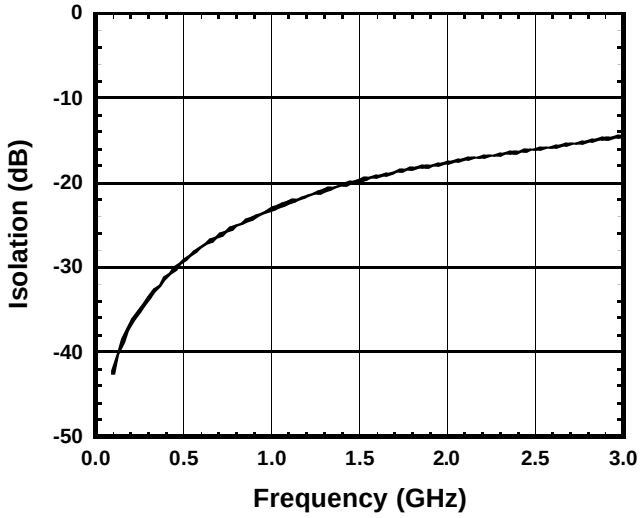
P3-P2 Insertion Loss vs. Frequency

(P1-P4/P3-P2 ON, VCTL=0V/2.8V, Pin=-10dBm)



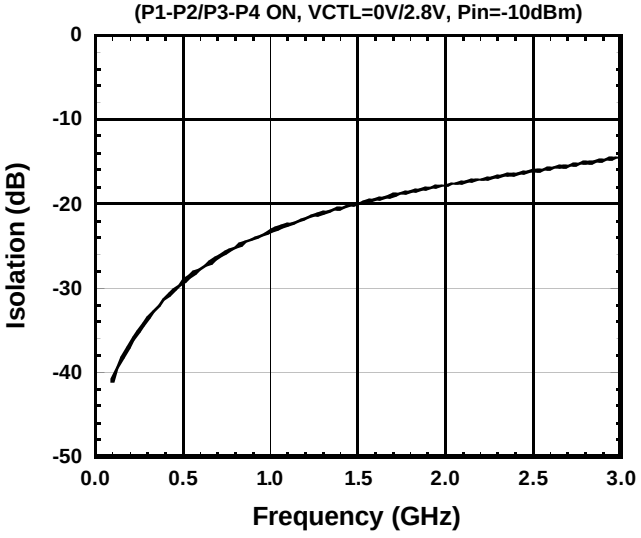
P1-P4 Isolation vs. Frequency

(P1-P2/P3-P4 ON, VCTL=0V/2.8V, Pin=-10dBm)



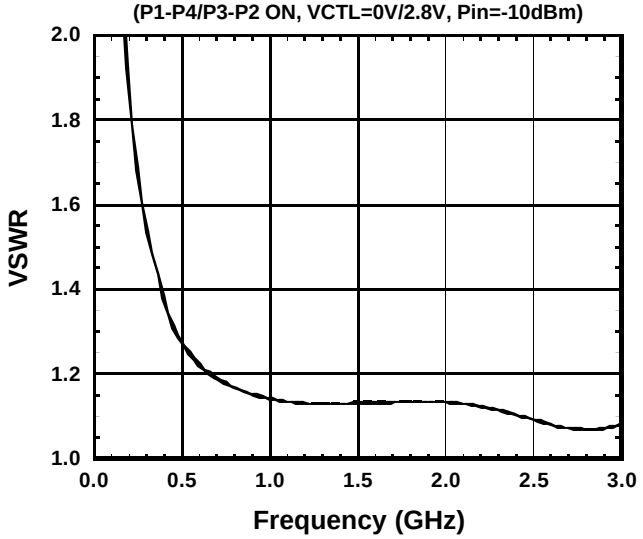
P3-P2 Isolation vs. Frequency

(P1-P2/P3-P4 ON, VCTL=0V/2.8V, Pin=-10dBm)



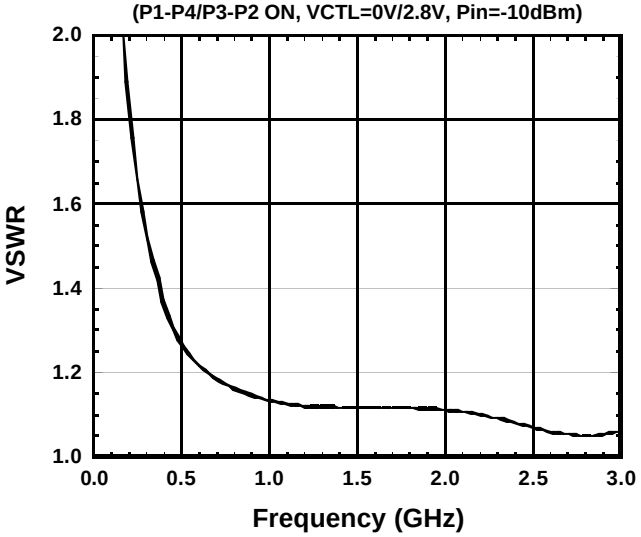
P1-P4 VSWR vs. Frequency

(P1-P4/P3-P2 ON, VCTL=0V/2.8V, Pin=-10dBm)



P3-P2 VSWR vs. Frequency

(P1-P4/P3-P2 ON, VCTL=0V/2.8V, Pin=-10dBm)

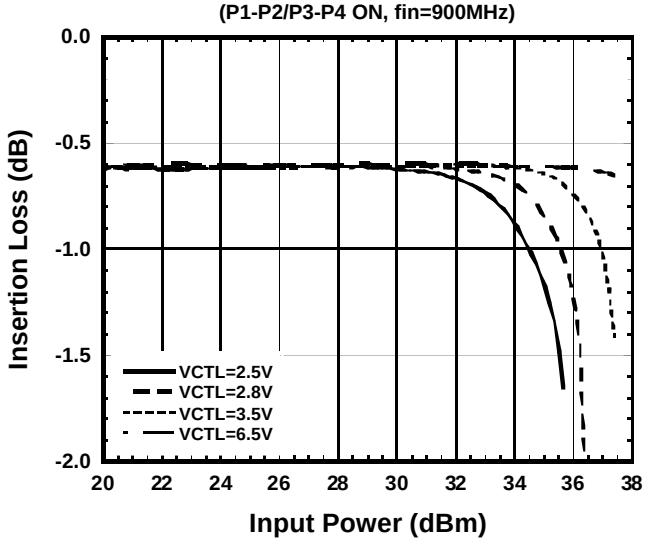


■ELECTRICAL CHARACTERISTICS

(with application circuit, losses of PCB, connector and DC blocking capacitor are excluded)

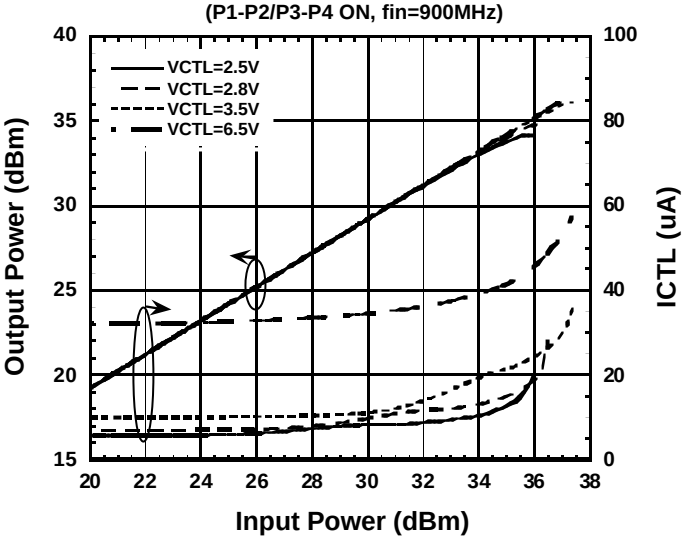
P1-P2 Insertion Loss vs. Input Power

(P1-P2/P3-P4 ON, fin=900MHz)



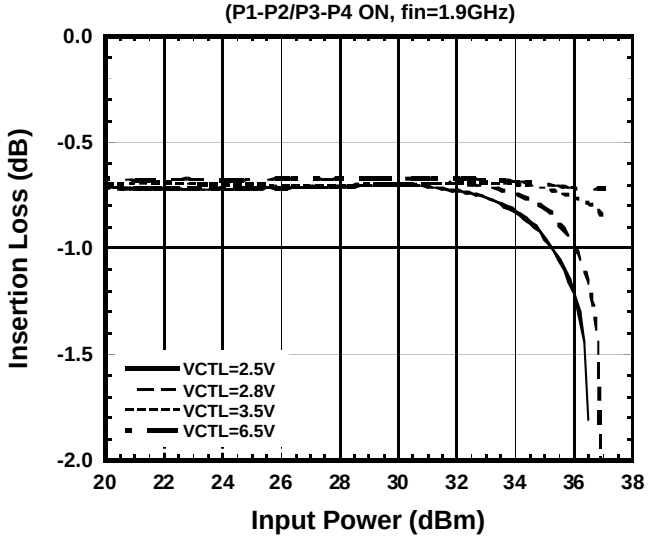
P1-P2 Output Power, ICTL vs. Input Power

(P1-P2/P3-P4 ON, fin=900MHz)



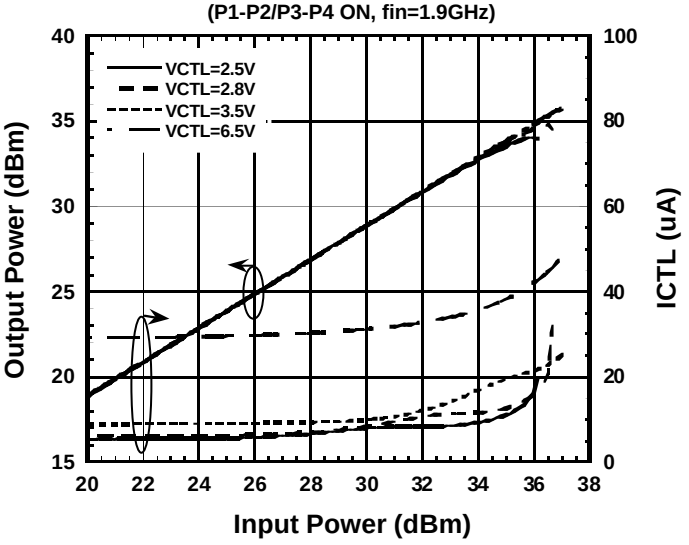
P1-P2 Insertion Loss vs. Input Power

(P1-P2/P3-P4 ON, fin=1.9GHz)

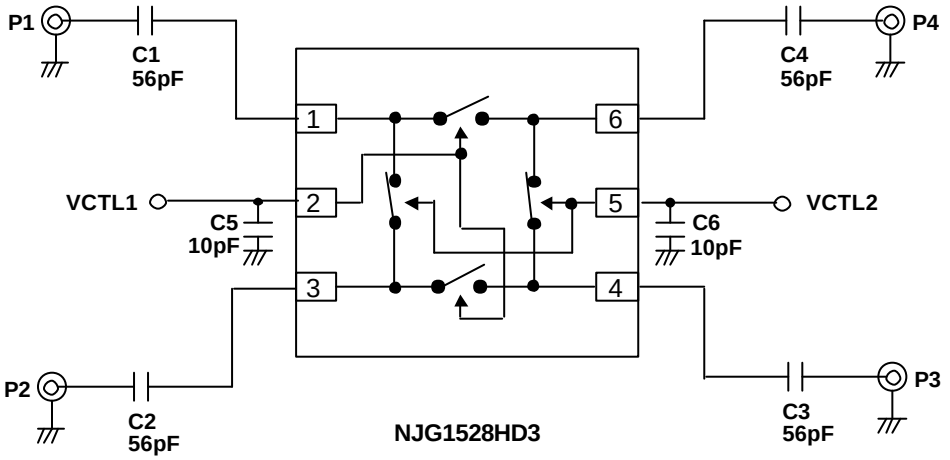


P1-P2 Output Power, ICTL vs. Input Power

(P1-P2/P3-P4 ON, fin=1.9GHz)



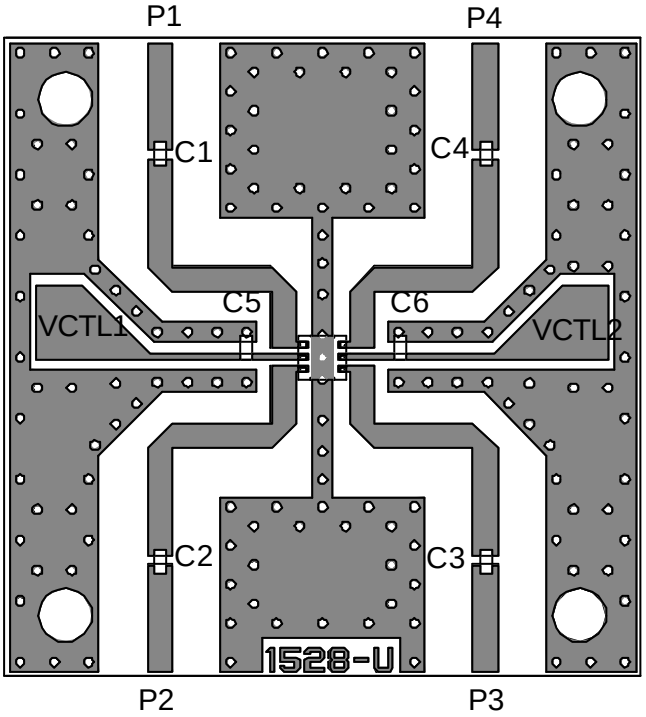
■APPLICATION CIRCUIT



PARTS LIST

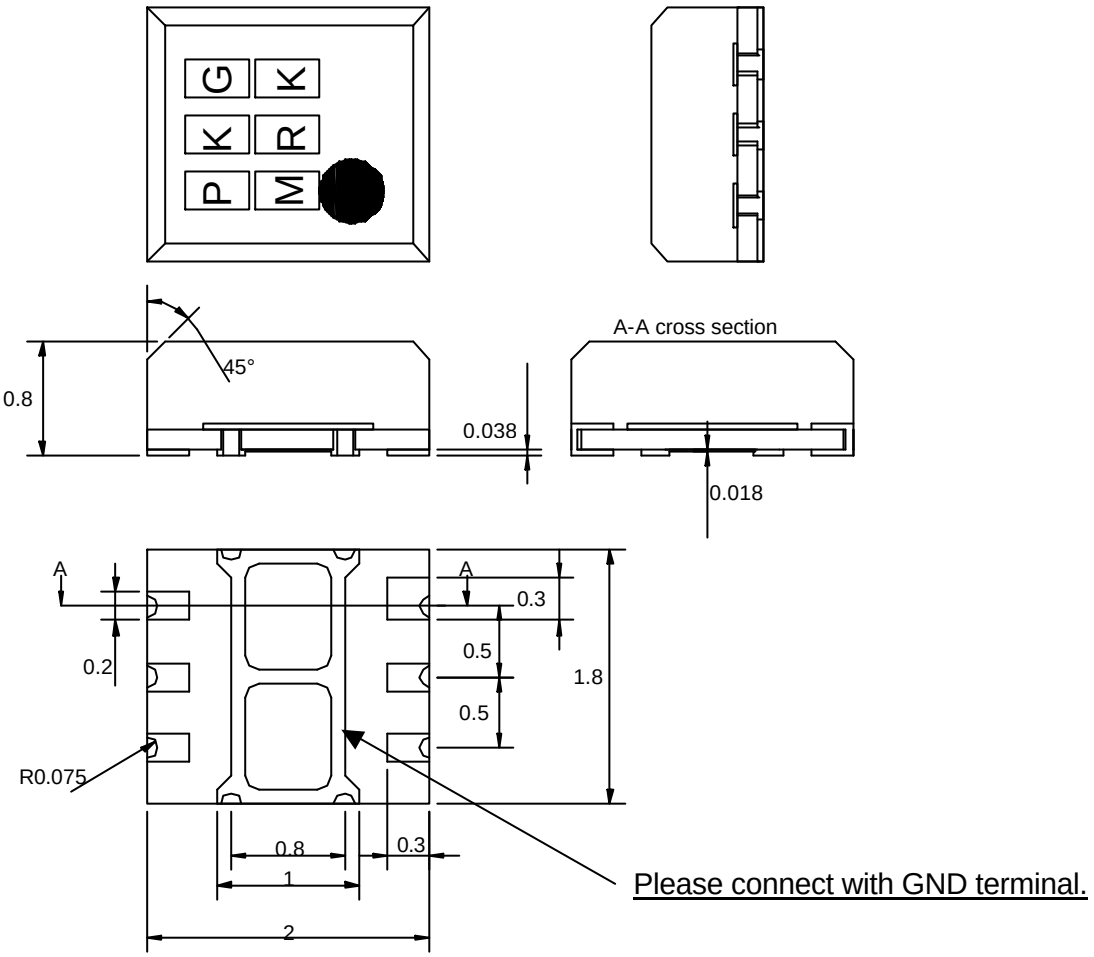
Parts No.	f=0.05-0.1GHz	f=0.1-0.5GHz	f=0.5-2.5GHz	Comment
C1 ~ C4	0.01uF	1000pF	56pF	MURATA (GRM36)
C5 ,C6	10pF	10pF	10pF	MURATA (GRM36)

■RECOMMENDED PCB DESIGN



PCB SIZE=26x26mm
PCB:FR-4 t=0.5mm
CAPACITOR:size 1005
MICROSTRIP LINE WIDTH=1.0mm(Zo=50ohm)

■ **PACKAGE OUTLINE** (USB10-D3)



TERMINAL TREAT	:Au
PCB	:FR5
Molding material	: Epoxy resin
UNIT	:mm
WEIGHT	:13mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.